

國立交通大學 107 學年度暑假博士班資格考 考試命題紙

科目：固態理論

系所別：電子研究所

第 1 頁共 2 頁

☐ 可看書 ☒ 不可看書(可使用計算機)

考試日期：107 年 8 月 7、8 日

Free electron mass = 9.1×10^{-31} kg; $\hbar = 1.05 \times 10^{-34}$ J/sec

1. To find the degree of space filling for a given lattice, first find the distance d_{\min} between nearest neighbors. Then put circles (in two dimensions) or spheres (in three dimensions) of diameter d_{\min} on each lattice site, and ask what portion of space is occupied by the circles or spheres. This number is the packing fraction.

(a) (4%) Calculate the packing fractions for the square and hexagonal lattices in two dimensions.

(b) (12%) Calculate the packing fractions for the following three-dimensional lattices: Simple cubic, body-centered cubic, face-centered cubic, and hexagonal close-packed.

2. (14%) Assume that a 3D metal has a simple cubic lattice with a lattice constant of 0.5 nm, and that each atom has one valence electron which becomes a conduction electron in the solid. Based on free electron model, estimate the Fermi energy for the metal.

3. Assume that E vs. k relationship for electrons in the conduction band of a n -type semiconductor can be approximated by

$$E = ak^2 + b,$$

where a and b are constants.

The cyclotron resonance for electrons in a field $B = 0.1$ Weber-m⁻² occurs at an angular frequency = 1.8×10^{11} rad s⁻¹.

(a) (10%) Find the value of a .

(b) (10%) Estimate the carrier concentration in the semiconductor, given that the Hall coefficient at room temperature is $R_H = 6.25 \times 10^{-6}$ m³coul⁻¹.

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4. Assuming that the crystal potential of a one-dimensional solid with lattice constant a is given by

$$U(x) = aV_0 \sum \delta(x-na), \text{ } n \text{ is an integer}$$

where V_0 is a positive constant. In the one-dimensional Kronig-Penny model, the electron $E-k$ relationship can be derived from the following equation

$$\cos(ka) = \cos(\alpha) + P \sin(\alpha)/\alpha, \text{ where } \alpha = (2ma^2E/\hbar^2)^{0.5} \text{ and } P = V_0ma^2/\hbar^2,$$

- (a) Please calculate the maximum energy in the first band and the corresponding k values. (5%)
- (b) Assuming V_0 is sufficiently small, please calculate the **minimum** energy in the second band and the corresponding k values. (hint, please use Taylor expansions $\cos(\alpha) \sim -1 + (\alpha - \pi)^2/2$ and $\sin(\alpha) \sim -(\alpha - \pi)$ as α is close to π .) (15%)
- (c) What is the bandgap energy from (b)? (5%)

5. Assume that an ionized impurity atom has an attracting potential as follows

$$U(x) = -1\text{eV} \quad \text{for } -a < x < a, \text{ and}$$

$$U(x) = 0\text{eV} \quad \text{elsewhere}$$

In a one-dimensional metal, assume that a free electron has a wave-vector k and the ionized impurity scattering is elastic.

- (a) What is the electron wave-vector after ionized impurity scattering? (5%)
- (b) Please calculate the ionized impurity scattering rate. Express your result in terms of k , a , π , .. (20%)